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## Voltage Regulator - Low Power Low, Dropout 100 mA

## LP2950, LP2951, NCV2951

The LP2950 and LP2951 are micropower voltage regulators that are specifically designed to maintain proper regulation with an extremely low input-to-output voltage differential. These devices feature a very low quiescent bias current of 75  $\mu$ A and are capable of supplying output currents in excess of 100 mA. Internal current and thermal limiting protection is provided.

The LP2951 has three additional features. The first is the Error Output that can be used to signal external circuitry of an out of regulation condition, or as a microprocessor power-on reset. The second feature allows the output voltage to be preset to 5.0 V, 3.3 V or 3.0 V output (depending on the version) or programmed from 1.25 Vto 29 V. It consists of a pinned out resistor divider along with direct access to the Error Amplifier feedback input. The third feature is a Shutdown input that allows a logic level signal to turn-off or turn-on the regulator output.

Due to the low input-to-output voltage differential and bias current specifications, these devices are ideally suited for battery powered computer, consumer, and industrial equipment where an extension of useful battery life is desirable. The LP2950 is available in the three pin case 29 and DPAK packages, and the LP2951 is available in the eight pin dual-in-line, SOIC-8 and Micro8 surface mount packages. The 'A' suffix devices feature an initial output voltage tolerance  $\pm 0.5\%$ .

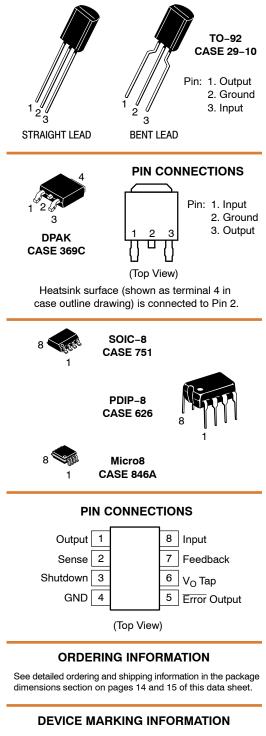
## Features

- Low Quiescent Bias Current of 75 μA
- $\bullet\,$  Low Input–to–Output Voltage Differential of 50 mV at 100  $\mu A$  and 380 mV at 100 mA
- 5.0 V, 3.3 V or 3.0 V  $\pm$ 0.5% Allows Use as a Regulator or Reference
- Extremely Tight Line and Load Regulation
- Requires Only a 1.0 µF Output Capacitor for Stability
- Internal Current and Thermal Limiting
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free and RoHS Compliant

## LP2951 Additional Features

- Error Output Signals an Out of Regulation Condition
- Output Programmable from 1.25 V to 29 V
- Logic Level Shutdown Input

(See Following Page for Device Information.)



See general marking information in the device marking section on page 16 of this data sheet.

## **DEVICE INFORMATION**

		Output V	oltage		Operating Ambient	
Package	3.0 V	Adjustable	Temperature Range			
	LP2950ACZ-3.0G	LP2950ACZ-3.3G	LP2950ACZ-5.0G			
	LP2950ACZ-3.0RAG	LP2950ACZ-3.3RAG	LP2950ACZ-5.0RAG			
TO-92 Suffix Z	LP2950CZ-3.0G	LP2950CZ-3.3G	LP2950CZ-5.0G	Not Available	$T_A = -40^\circ$ to $+125^\circ$ C	
			LP2950CZ-5.0RAG			
	LP2950CZ-3.0RAG	LP2950CZ-3.3RAG	LP2950CZ-5.0RPG			
		LP2950ACDT-3.3RG	LP2950ACDT-5.0G			
DPAK	LP2950CDT-3.0RKG	LP2950CDT-3.3G	LP2950ACDT-5RKG	Net Austlahla	$T_A = -40^\circ$ to +125°C	
Suffix DT		LP2950CDT-3.3RKG	LP2950CDT-5.0G	Not Available		
			LP2950CDT-5.0RKG			
	LP2951ACD-3.0R2G	LP2951ACD-3.3R2G	LP2951ACDR2G	LP2951ACDR2G		
SOIC-8		LP2951CD-3.3R2G	LP2951CDR2G	LP2951CDR2G	T 400 L 40500	
Suffix D	LP2951CD-3.0R2G		NCV2951ACDR2G*	NCV2951ACDR2G*	$T_{A} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	
		NCV2951ACD-3.3R2G*	NCV2951CDR2G*	NCV2951CDR2G*		
			LP2951ACDMR2G	LP2951ACDMR2G		
Micro8 Suffix DM	LP2951ACDM-3.0RG	LP2951ACDM-3.3RG	LP2951CDMR2G	LP2951CDMR2G	$T_A = -40^\circ$ to $+125^\circ$ C	
			NCV2951ACDMR2G*	NCV2951ACDMR2G*		

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

LP2950Cx-xx / LP2951Cxx-xx / NCV2951Cx-xx 1% Output Voltage Precision at T<sub>A</sub> = 25°C

LP2950ACx-xx / LP2951ACxx-xx / NCV2951Ax-xx 0.5% Output Voltage Precision at  $T_A = 25^{\circ}C$ 

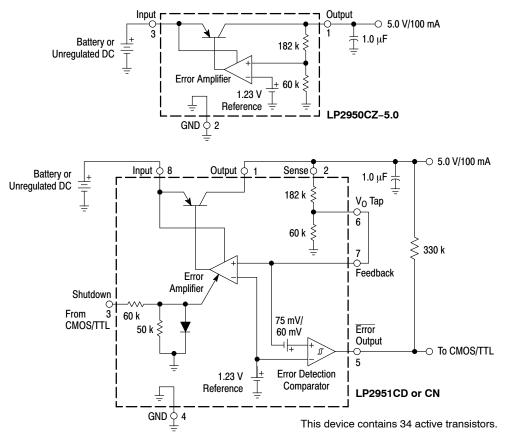


Figure 1. Representative Block Diagrams

## **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ , unless otherwise noted.)

Rating	Symbol	Value	Unit
Input Voltage	V <sub>CC</sub>	30	Vdc
Peak Transient Input Voltage (t < 300 ms)	V <sub>CC</sub>	32	Vdc
Power Dissipation and Thermal Characteristics			
Maximum Power Dissipation	PD	Internally Limited	W
Case 751 (SOIC-8) D Suffix			
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	180	°C/W
Thermal Resistance, Junction-to-Case	$R_{ ext{ heta}JC}$	45	°C/W
Case 369A (DPAK) DT Suffix (Note 1)			
Thermal Resistance, Junction-to-Ambient	$R_{ hetaJA}$	92	°C/W
Thermal Resistance, Junction-to-Case	$R_{ ext{ heta}JC}$	6.0	°C/W
Case 29 (TO-226AA/TO-92) Z Suffix			
Thermal Resistance, Junction-to-Ambient	$R_{ hetaJA}$	160	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83	°C/W
Case 626 N Suffix			
Thermal Resistance, Junction-to-Ambient	$R_{ hetaJA}$	105	°C/W
Case 846A (Micro8) DM Suffix			
Thermal Resistance, Junction-to-Ambient	$R_{ ext{ heta}JA}$	240	°C/W
Feedback Input Voltage	V <sub>fb</sub>	-1.5 to +30	Vdc
Shutdown Input Voltage	V <sub>sd</sub>	-0.3 to +30	Vdc
Error Comparator Output Voltage	V <sub>err</sub>	–0.3 to +30	Vdc
Operating Ambient Temperature Range	T <sub>A</sub>	-40 to +125	°C
Maximum Die Junction Temperature Range	TJ	+150	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### **ELECTRICAL CHARACTERISTICS**

(V<sub>in</sub> = V<sub>O</sub> + 1.0 V, I<sub>O</sub> = 100  $\mu$ A, C<sub>O</sub> = 1.0  $\mu$ F, T<sub>A</sub> = 25°C [Note 3], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage, 5.0 V Versions	Vo				V
$V_{in} = 6.0 \text{ V}, I_O = 100 \ \mu\text{A}, T_A = 25^{\circ}\text{C}$					
LP2950C-5.0/LP2951C/NCV2951C*		4.950	5.000	5.050	
LP2950AC-5.0/LP2951AC/NCV2951AC*		4.975	5.000	5.025	
$T_{A} = -40 \text{ to } +125^{\circ}\text{C}$					
LP2950C-5.0/LP2951C/NCV2951C*		4.900	-	5.100	
LP2950AC-5.0/LP2951AC/NCV2951AC*		4.940	-	5.060	
$V_{in}$ = 6.0 to 30 V, I <sub>O</sub> = 100 $\mu$ A to 100 mA, T <sub>A</sub> = -40 to +125°C					
LP2950C-5.0/LP2951C/NCV2951C*		4.880	-	5.120	
LP2950AC-5.0/LP2951AC/NCV2951AC*		4.925	-	5.075	
Output Voltage, 3.3 V Versions	Vo				V
$V_{in}$ = 4.3 V, $I_O$ = 100 $\mu$ A, $T_A$ = 25°C					
LP2950C-3.3/LP2951C-3.3		3.267	3.300	3.333	
LP2950AC-3.3/LP2951AC-3.3/NCV2951AC-3.3*		3.284	3.300	3.317	
$T_{A} = -40 \text{ to } +125^{\circ}\text{C}$					
LP2950C-3.3/LP2951C-3.3		3.234	-	3.366	
LP2950AC-3.3/LP2951AC-3.3/NCV2951AC-3.3*		3.260	-	3.340	
$V_{in}$ = 4.3 to 30 V, $I_O$ = 100 $\mu A$ to 100 mA, $T_A$ = $-40$ to $+125^\circ C$					
LP2950C-3.3/LP2951C-3.3		3.221	-	3.379	
LP2950AC-3.3/LP2951AC-3.3/NCV2951AC-3.3*		3.254	-	3.346	
Output Voltage, 3.0 V Versions	Vo				V
$V_{in}$ = 4.0 V, $I_O$ = 100 $\mu$ A, $T_A$ = 25°C					
LP2950C-3.0/LP2951C-3.0		2.970	3.000	3.030	
LP2950AC-3.0/LP2951AC-3.0		2.985	3.000	3.015	
$T_{A} = -40 \text{ to } +125^{\circ}\text{C}$					
LP2950C-3.0/LP2951C-3.0		2.940	-	3.060	
LP2950AC-3.0/LP2951AC-3.0		2.964	-	3.036	
$V_{in}$ = 4.0 to 30 V, $I_O$ = 100 $\mu A$ to 100 mA, $T_A$ = – 40 to +125°C					
LP2950C-3.0/LP2951C-3.0		2.928	-	3.072	
LP2950AC-3.0/LP2951AC-3.0		2.958	-	3.042	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. The Junction-to-Ambient Thermal Resistance is determined by PCB copper area per Figure 29.

This device series contains ESD protection and exceeds the following tests: Human Body Model (HBM), 2000 V, Class 2, JESD22 A114–C Machine Model (MM), 200 V, Class B, JESD22 A115–A

Charged Device Model (CDM), 2000 V, Class IV, JESD22 C101-C

3. Low duty pulse techniques are used during test to maintain junction temperature as close to ambient as possible.

4. V<sub>O(nom)</sub> is the part number voltage option.

5. Noise tests on the LP2951 are made with a 0.01  $\mu$ F capacitor connected across Pins 7 and 1.

6. Latch-up Current Maximum Rating tested per JEDEC standard: JESD78

Inputs Low: passing positive current 100 mA and negative current –100 mA

- Inputs High: passing positive current 100 mA and negative current -10 mA.

\*NCV prefix is for automotive and other applications requiring site and change control.

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#### ELECTRICAL CHARACTERISTICS (continued)

(V<sub>in</sub> = V<sub>O</sub> + 1.0 V, I<sub>O</sub> = 100  $\mu$ A, C<sub>O</sub> = 1.0  $\mu$ F, T<sub>A</sub> = 25°C [Note 9], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Line Regulation (V <sub>in</sub> = V <sub>O(nom)</sub> +1.0 V to 30 V) (Note 10) LP2950C-XX/LP2951C/LP2951C-XX/NCV2951C*	Reg <sub>line</sub>	_	0.08	0.20	%
LP2950AC-XX/LP2951AC/LP2951AC-XX/NCV2951AC*		_	0.04	0.10	
Load Regulation ( $I_{O}$ = 100 $\mu$ A to 100 mA)	Reg <sub>load</sub>				%
LP2950C-XX/LP2951C/LP2951C-XX/NCV2951C*	olodd	-	0.13	0.20	
LP2950AC-XX/LP2951AC/LP2951AC-XX/NCV2951AC*		-	0.05	0.10	
Dropout Voltage	V <sub>I</sub> – V <sub>O</sub>				mV
I <sub>O</sub> = 100 μA		-	30	80	
I <sub>O</sub> = 100 mA		-	350	450	
Supply Bias Current	I <sub>CC</sub>				
$I_0 = 100 \mu\text{A}$		-	93	120	μΑ
$I_0 = 100 \text{ mA}$	<u> </u>	-	4.0	12	mA
Dropout Supply Bias Current (Vin = V_O(nom) - 0.5 V, $I_O$ = 100 $\mu A)$ (Note 10)	I <sub>CCdropout</sub>	-	110	170	μΑ
Current Limit (V <sub>O</sub> Shorted to Ground)	I <sub>Limit</sub>	-	220	300	mA
Thermal Regulation	Reg <sub>thermal</sub>	-	0.05	0.20	%/W
Output Noise Voltage (10 Hz to 100 kHz) (Note 11)	V <sub>n</sub>				μVrms
$C_L = 1.0 \ \mu F$		-	126	-	
C <sub>L</sub> = 100 μF		-	56	-	
P2951A/LP2951AC Only				-	
Reference Voltage (T <sub>A</sub> = 25°C)	V <sub>ref</sub>				V
LP2951C/LP2951C-XX/NCV2951C*		1.210	1.235	1.260	
LP2951AC/LP2951AC-XX/NCV2951AC*		1.220	1.235	1.250	
Reference Voltage ( $T_A = -40$ to $+125$ °C)	V <sub>ref</sub>	1 000		1 070	V
LP2951C/LP2951C-XX/NCV2951C* LP2951AC/LP2951AC-XX/NCV2951AC*		1.200 1.200	-	1.270	
	N	1.200	-	1.260	
Reference Voltage ( $T_A = -40 \text{ to } +125^{\circ}\text{C}$ ) I <sub>O</sub> = 100 $\mu$ A to 100 mA, V <sub>in</sub> = 23 to 30 V	V <sub>ref</sub>				V
LP2951C/LP2951C-XX/NCV2951C*		1.185	_	1.285	
LP2951AC/LP2951AC-XX/NCV2951AC*		1.190	-	1.270	
Feedback Pin Bias Current	I <sub>FB</sub>	_	15	40	nA
Error Comparator					
Output Leakage Current (V <sub>OH</sub> = 30 V)	l <sub>lkg</sub>	-	0.01	1.0	μA
Output Low Voltage (V <sub>in</sub> = 4.5 V, $I_{OL}$ = 400 $\mu$ A)	V <sub>OL</sub>	-	150	250	mV
Upper Threshold Voltage (V <sub>in</sub> = 6.0 V)	V <sub>thu</sub>	40	45	_	mV
Lower Threshold Voltage (V <sub>in</sub> = 6.0 V)	V <sub>thl</sub>	-	60	95	mV
Hysteresis (V <sub>in</sub> = 6.0 V)	V <sub>hy</sub>	-	15	-	mV
Shutdown Input					
Input Logic Voltage	V <sub>shtdn</sub>				V
Logic "0" (Regulator "On")	Silui	0	-	0.7	
Logic "1" (Regulator "Off")		2.0	-	30	1
Shutdown Pin Input Current	I <sub>shtdn</sub>				μA
V <sub>shtdn</sub> = 2.4 V		-	35	50	
V <sub>shtdn</sub> = 30 V		-	450	600	
Regulator Output Current in Shutdown Mode ( $V_{in} = 30 V$ , $V_{shtdn} = 2.0 V$ , $V_O = 0$ , Pin 6 Connected to Pin 7)	I <sub>off</sub>	-	3.0	10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. The Junction-to-Ambient Thermal Resistance is determined by PCB copper area per Figure 29.

8. ESD data available upon request.

9. Low duty pulse techniques are used during test to maintain junction temperature as close to ambient as possible.

10.  $V_{O(nom)}$  is the part number voltage option. 11. Noise tests on the LP2951 are made with a 0.01  $\mu$ F capacitor connected across Pins 7 and 1.

\*NCV prefix is for automotive and other applications requiring site and change control.

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#### DEFINITIONS

**Dropout Voltage** – The input/output voltage differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 100 mV below its nominal value (which is measured at 1.0 V differential), dropout voltage is affected by junction temperature, load current and minimum input supply requirements.

**Line Regulation** – The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that average chip temperature is not significantly affected.

**Load Regulation** – The change in output voltage for a change in load current at constant chip temperature.

**Maximum Power Dissipation** – The maximum total device dissipation for which the regulator will operate within specifications.

**Bias Current** – Current which is used to operate the regulator chip and is not delivered to the load.

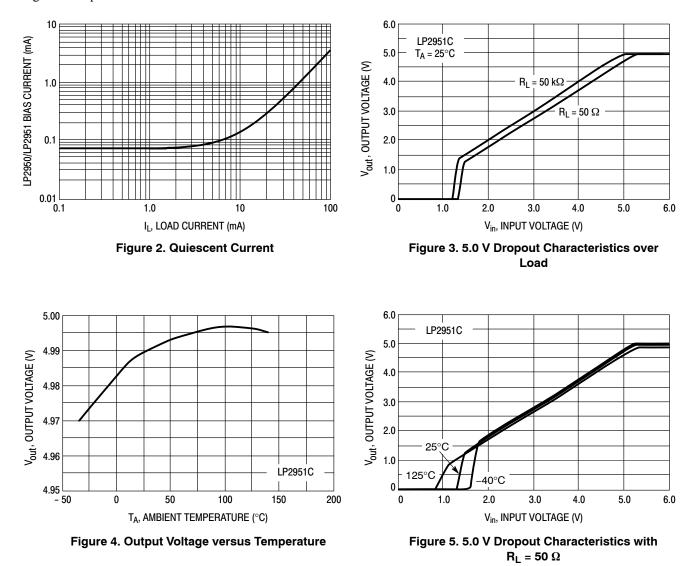
**Output Noise Voltage** – The RMS ac voltage at the output, with constant load and no input ripple, measured over a specified frequency range.

**Leakage Current** – Current drawn through a bipolar transistor collector–base junction, under a specified collector voltage, when the transistor is "off".

**Upper Threshold Voltage** – Voltage applied to the comparator input terminal, below the reference voltage which is applied to the other comparator input terminal, which causes the comparator output to change state from a logic "0" to "1".

**Lower Threshold Voltage** – Voltage applied to the comparator input terminal, below the reference voltage which is applied to the other comparator input terminal, which causes the comparator output to change state from a logic "1" to "0".

**Hysteresis** – The difference between Lower Threshold voltage and Upper Threshold voltage.



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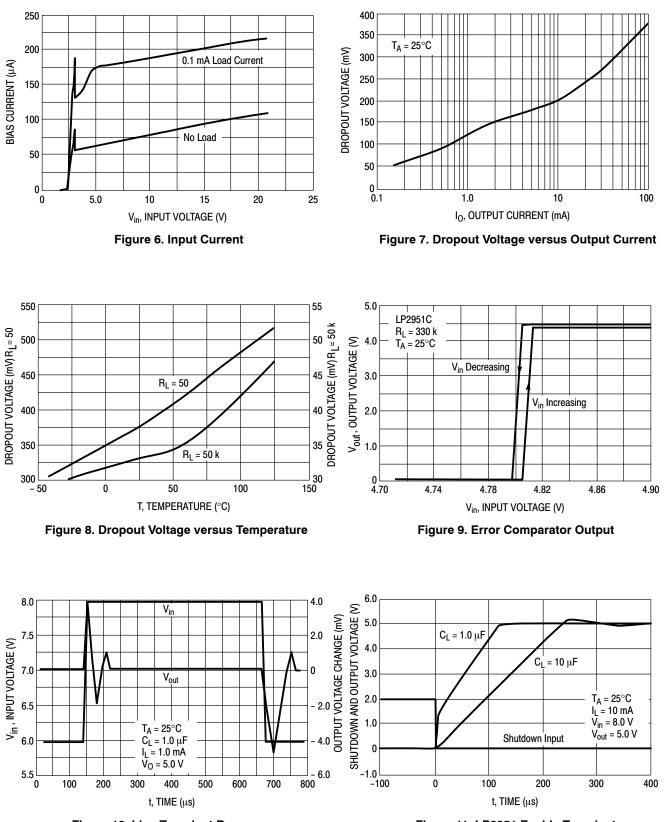
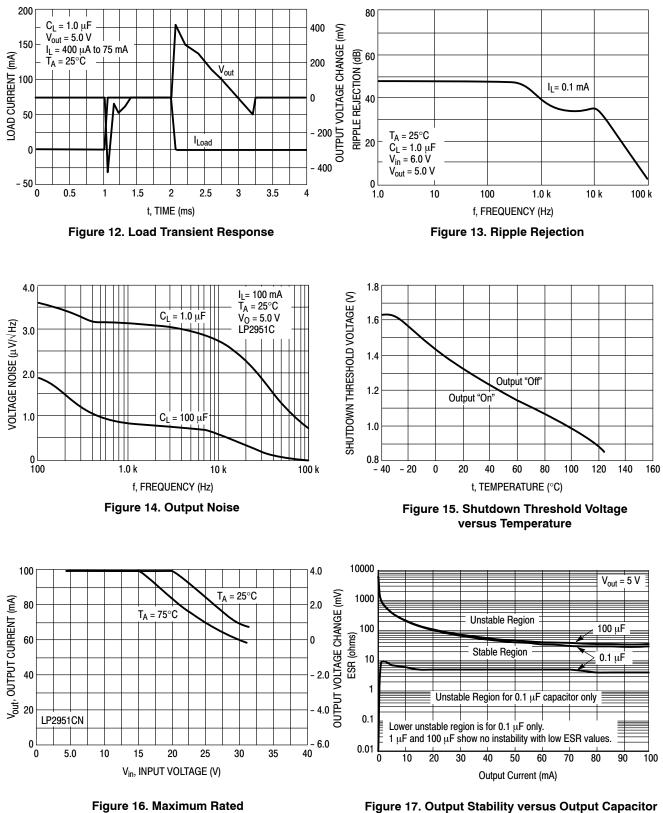


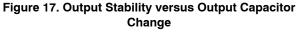


Figure 11. LP2951 Enable Transient

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## **APPLICATIONS INFORMATION**

#### Introduction

The LP2950/LP2951 regulators are designed with internal current limiting and thermal shutdown making them user-friendly. Typical application circuits for the LP2950 and LP2951 are shown in Figures 20 through 28.

These regulators are not internally compensated and thus require a 1.0  $\mu$ F (or greater) capacitance between the LP2950/LP2951 output terminal and ground for stability. Most types of aluminum, tantalum or multilayer ceramic will perform adequately. Solid tantalums or appropriate multilayer ceramic capacitors are recommended for operation below 25°C.

At lower values of output current, less output capacitance is required for output stability. The capacitor can be reduced to 0.33  $\mu$ F for currents less than 10 mA, or 0.1  $\mu$ F for currents below 1.0 mA. Using the 8 pin versions at voltages less than 5.0 V operates the error amplifier at lower values of gain, so that more output capacitance is needed for stability. For the worst case operating condition of a 100 mA load at 1.23 V output (output Pin 1 connected to the feedback Pin 7) a minimum capacitance of 3.3  $\mu$ F is recommended.

The LP2950 will remain stable and in regulation when operated with no output load. When setting the output voltage of the LP2951 with external resistors, the resistance values should be chosen to draw a minimum of  $1.0 \,\mu$ A.

A bypass capacitor is recommended across the LP2950/LP2951 input to ground if more than 4 inches of wire connects the input to either a battery or power supply filter capacitor.

Input capacitance at the LP2951 Feedback Pin 7 can create a pole, causing instability if high value external resistors are used to set the output voltage. Adding a 100 pF capacitor between the Output Pin 1 and the Feedback Pin 7 and increasing the output filter capacitor to at least  $3.3 \,\mu\text{F}$  will stabilize the feedback loop.

#### **Error Detection Comparator**

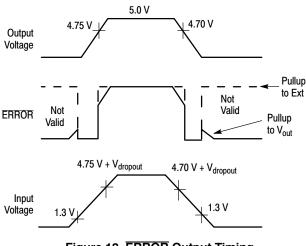
The comparator switches to a positive logic low whenever the LP2951 output voltage falls more than approximately 5.0% out of regulation. This value is the comparator's designed-in offset voltage of 60 mV divided by the 1.235 V internal reference. As shown in the representative block diagram. This trip level remains 5.0% below normal regardless of the value of regulated output voltage. For example, the error flag trip level is 4.75 V for a normal 5.0 V regulated output, or 9.50 V for a 10 V output voltage.

Figure 2 is a timing diagram which shows the ERROR signal and the regulated output voltage as the input voltage

to the LP2951 is ramped up and down. The ERROR signal becomes valid (low) at about 1.3 V input. It goes high when the input reaches about 5.0 V ( $V_{out}$  exceeds about 4.75 V). Since the LP2951's dropout voltage is dependent upon the load current (refer to the curve in the Typical Performance Characteristics), the input voltage trip point will vary with load current. The output voltage trip point does not vary with load.

The error comparator output is an open collector which requires an external pullup resistor. This resistor may be returned to the output or some other voltage within the system. The resistance value should be chosen to be consistent with the 400  $\mu$ A sink capability of the error comparator. A value between 100 k $\Omega$  and 1.0 M $\Omega$  is suggested. No pullup resistance is required if this output is unused.

When operated in the power down mode ( $V_{in} = 0 V$ ), the error comparator output will go high if it has been pulled up to an external supply (the output transistor is in high impedance state). To avoid this invalid response, the error comparator output should be pulled up to  $V_{out}$  (see Figure 18).





#### Programming the Output Voltage (LP2951)

The LP2951CX may be pin-strapped for the nominal fixed output voltage using its internal voltage divider by tying Pin 1 (output) to Pin 2 (sense) and Pin 7 (feedback) to Pin 6 (5.0 V tap). Alternatively, it may be programmed for any output voltage between its 1.235 reference voltage and its 30 V maximum rating. An external pair of resistors is required, as shown in Figure 19.

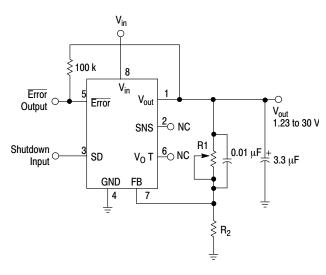


Figure 19. Adjustable Regulator

The complete equation for the output voltage is:

where  $V_{ref}$  is the nominal 1.235 V reference voltage and  $I_{FB}$  is the feedback pin bias current, nominally -20 nA. The minimum recommended load current of 1.0  $\mu$ A forces an upper limit of 1.2 M $\Omega$  on the value of R2, if the regulator must work with no load.  $I_{FB}$  will produce a 2% typical error in  $V_{out}$  which may be eliminated at room temperature by adjusting R1. For better accuracy, choosing R2 = 100 k reduces this error to 0.17% while increasing the resistor program current to 12  $\mu$ A. Since the LP2951 typically draws 75  $\mu$ A at no load with Pin 2 open circuited, the extra 12  $\mu$ A of current drawn is often a worthwhile tradeoff for eliminating the need to set output voltage in test.

#### **Output Noise**

In many applications it is desirable to reduce the noise present at the output. Reducing the regulator bandwidth by increasing the size of the output capacitor is the only method for reducing noise on the 3 lead LP2950. However, increasing the capacitor from 1.0  $\mu$ F to 220  $\mu$ F only decreases the noise from 430  $\mu$ V to 160  $\mu$ Vrms for a 100 kHz bandwidth at the 5.0 V output.

Noise can be reduced fourfold by a bypass capacitor across R1, since it reduces the high frequency gain from 4 to unity. Pick

$$C_{Bypass} \approx \frac{1}{2\pi R1 \times 200 \text{ Hz}}$$

or about 0.01  $\mu$ F. When doing this, the output capacitor must be increased to 3.3  $\mu$ F to maintain stability. These changes reduce the output noise from 430  $\mu$ V to 126  $\mu$ Vrms for a 100 kHz bandwidth at 5.0 V output. With bypass capacitor added, noise no longer scales with output voltage so that improvements are more dramatic at higher output voltages.

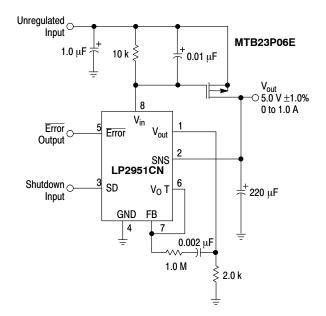
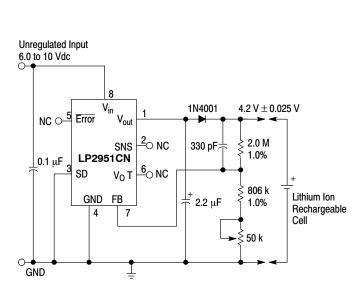


Figure 20. 1.0 A Regulator with 1.2 V Dropout

## **TYPICAL APPLICATIONS**





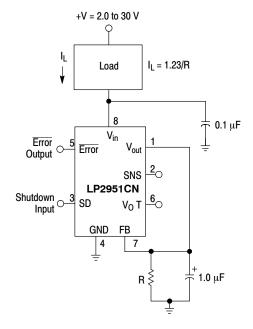
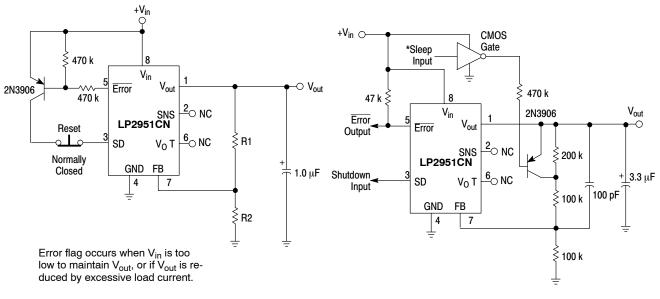
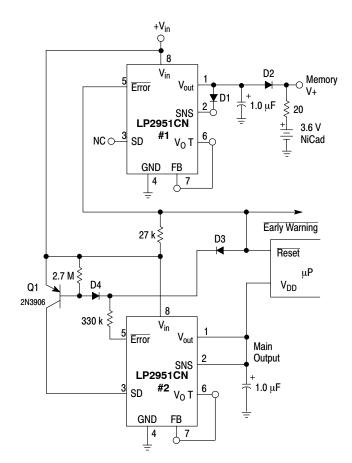


Figure 22. Low Drift Current Sink









All diodes are 1N4148.

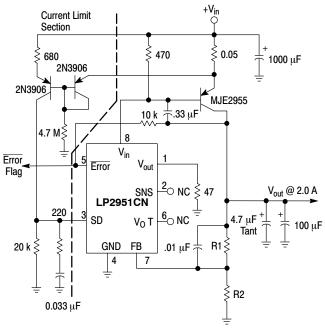
Early Warning flag on low input voltage.

Main output latches off at lower input voltages.

Battery backup on auxiliary output.

Operation: Regulator #1's V<sub>out</sub> is programmed one diode drop above 5.0 V. Its error flag becomes active when V<sub>in</sub>  $\leq$  5.7 V. When V<sub>in</sub> drops below 5.3 V, the error flag of regulator #2 becomes active and via Q1 latches the main output "off". When V<sub>in</sub> again exceeds 5.7 V, regulator #1 is back in regulation and the early warning signal rises, unlatching regulator #2 via D3.





Vout = 1.25V (1.0 + R1/R2)

For 5.0 V output, use internal resistors. Wire Pin 6 to 7, and wire Pin 2 to +V\_{out} Bus.



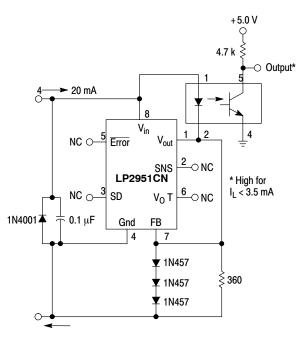
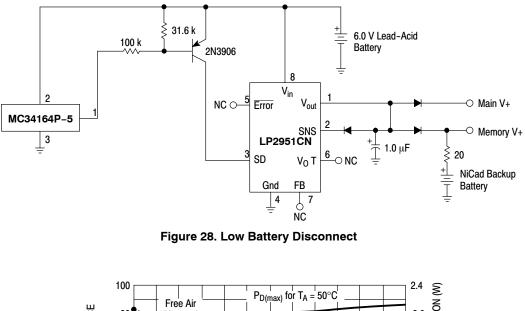
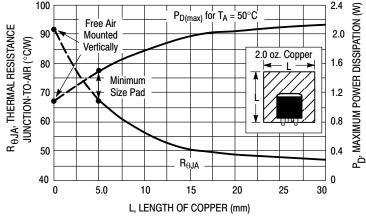


Figure 27. Open Circuit Detector for 4.0 to 20 mA Current Loop







<u>www.onsemi.com</u> 13

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## **ORDERING INFORMATION (LP2950)**

Part Number	Output Voltage (Volts)	Tolerance (%)	Package	Shipping <sup>†</sup>
LP2950CZ-3.0G	3.0	1.0	TO-92 (Pb-Free)	2000 Units / Bag
LP2950CZ-3.0RAG	3.0	1.0	TO-92 (Pb-Free)	2000 Units / Tape & Reel
LP2950ACZ-3.0G	3.0	0.5	TO-92 (Pb-Free)	2000 Units / Bag
LP2950ACZ-3.0RAG	3.0	0.5	TO-92 (Pb-Free)	2000 Units / Tape & Reel
LP2950CZ-3.3G	3.3	1.0	TO-92 (Pb-Free)	2000 Units / Bag
LP2950CZ-3.3RAG	3.3	1.0	TO-92 (Pb-Free)	2000 Units / Tape & Reel
LP2950ACZ-3.3G	3.3	0.5	TO-92 (Pb-Free)	2000 Units / Bag
LP2950ACZ-3.3RAG	3.3	0.5	TO-92 (Pb-Free)	2000 Units / Tape & Reel
LP2950CZ-5.0G	5.0	1.0	TO-92 (Pb-Free)	2000 Units / Bag
LP2950CZ-5.0RAG	5.0	1.0	TO-92 (Pb-Free)	2000 Units / Tape & Reel
LP2950CZ-5.0RPG	5.0	1.0	TO-92 (Pb-Free)	2000 Units / Ammo Pack
LP2950ACZ-5.0G	5.0	0.5	TO-92 (Pb-Free)	2000 Units / Bag
LP2950ACZ-5.0RAG	5.0	0.5	TO–92 (Pb–Free)	2000 Units / Tape & Reel
LP2950CDT-3.0RKG	3.0	1.0	DPAK (Pb–Free)	2500 Units / Tape & Reel
LP2950CDT-3.3G	3.3	1.0	DPAK (Pb-Free)	75 Units / Rail
LP2950CDT-3.3RKG	3.3	1.0	DPAK (Pb-Free)	2500 Units / Tape & Reel
LP2950ACDT-3.3RG	3.3	0.5	DPAK (Pb-Free)	2500 Units / Tape & Reel
LP2950CDT-5.0G	5.0	1.0	DPAK (Pb-Free)	75 Units / Rail
LP2950CDT-5.0RKG	5.0	1.0	DPAK (Pb-Free)	2500 Units / Tape & Reel
LP2950ACDT-5.0G	5.0	0.5	DPAK (Pb-Free)	75 Units / Rail
LP2950ACDT-5RKG	5.0	0.5	DPAK (Pb-Free)	2500 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ORDERING INFORMATION (LP2951)**

Part Number	Output Voltage (Volts)	Tolerance (%)	Package	Shipping <sup>†</sup>
LP2951CD-3.0R2G	3.0	1.0	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
LP2951ACD-3.0R2G	3.0	0.5	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
LP2951CD-3.3R2G	3.3	1.0	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
LP2951ACD-3.3G	3.3	0.5	SOIC-8 (Pb-Free)	98 Units / Rail
LP2951ACD-3.3R2G	3.3	0.5	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
LP2951CDG	5.0 or Adj.	1.0	SOIC-8 (Pb-Free)	98 Units / Rail
LP2951CDR2G	5.0 or Adj.	1.0	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
LP2951ACDG	5.0 or Adj.	0.5	SOIC-8 (Pb-Free)	98 Units / Rail
LP2951ACDR2G	5.0 or Adj.	0.5	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
LP2951ACDM-3.0RG	3.0	0.5	Micro8 (Pb–Free)	4000 Units / Tape & Reel
LP2951ACDM-3.3RG	3.3	0.5	Micro8 (Pb–Free)	4000 Units / Tape & Reel
LP2951CDMR2G	5.0 or Adj.	1.0	Micro8 (Pb-Free)	4000 Units / Tape & Reel
LP2951ACDMR2G	5.0 or Adj.	0.5	Micro8 (Pb–Free)	4000 Units / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

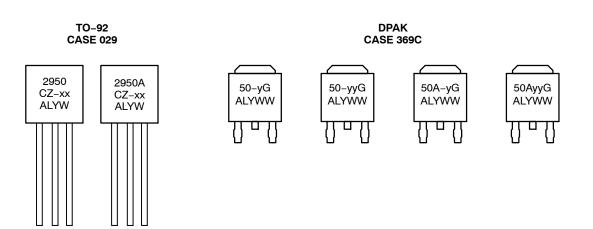
## **ORDERING INFORMATION (NCV2951)**

Part Number	Output Voltage (Volts)	Tolerance (%)	Package	Shipping <sup>†</sup>
NCV2951ACD3.3R2G*	3.3	0.5	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
NCV2951ACDR2G*	5.0 or Adj.	0.5	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
NCV2951CDR2G*	5.0 or Adj.	1.0	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
NCV2951ACDMR2G*	5.0 or Adj.	0.5	Micro8 (Pb–Free)	4000 Units / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

## MARKING DIAGRAMS



SOIC-8 CASE 751

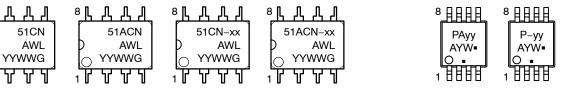
8 <u> </u>	8	<u>AAAA</u>		8 <u> </u>
51z	*	51z-33	*	51z-3
ALYW		ALYW		ALYW
	1			

PDIP-8 CASE 626

8 [

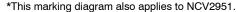
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Micro8 CASE 846A



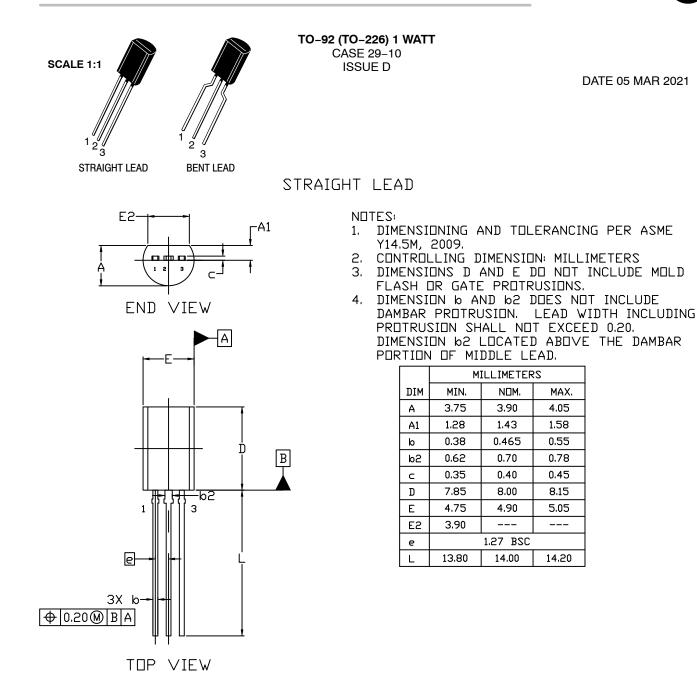
xx	= 3.0, 3.3, or 5.0
у	= 3 or 5
уу	= 30, 33, or 50
z	= A or C
А	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week
G	= Pb-Free Package
	= Pb-Free Package
(Noto: M	lieredet may be in either lees

(Note: Microdot may be in either location)



## MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





## **STYLES AND MARKING ON PAGE 3**

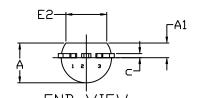
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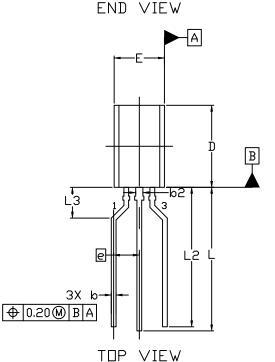


#### TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE D

DATE 05 MAR 2021

FORMED LEAD





## NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS.
- 4. DIMENSION № AND №2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION №2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

	MILLIMETERS				
DIM	MIN.	NDM.	MAX.		
Α	3.75	3.90	4.05		
A1	1.28	1.43	1.58		
b	0.38	0.465	0.55		
b2	0.62	0.70	0.78		
с	0.35	0.40	0.45		
D	7.85	8.00	8.15		
Е	4.75	4.90	5.05		
E2	3.90				
e	2.50 BSC				
L	13.80	14.00	14.20		
L2	13.20	13.60	14.00		
L3		3.00 REF			

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#### TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE D

## DATE 05 MAR 2021

STYLE 5: PIN 1. DRAIN

2.	EMITTER BASE COLLECTOR
	GATE SOURCE & SUBSTRATE DRAIN
2.	ANODE CATHODE & ANODE CATHODE
2.	ANODE GATE CATHODE
2.	COLLECTOR EMITTER BASE
	V <sub>CC</sub> GROUND 2 OUTPUT

	BASE EMITTER COLLECTOR
2.	SOURCE DRAIN GATE
2.	MAIN TERMINAL 1 Gate Main Terminal 2
2.	COLLECTOR BASE EMITTER
2.	Source Gate Drain
STYLE 27: PIN 1. 2. 3.	

2.	ANODE ANODE CATHODE
2.	DRAIN GATE SOURCE & SUBSTRATE
2.	ANODE 1 GATE CATHODE 2
2.	ANODE CATHODE NOT CONNECTED
	GATE SOURCE DRAIN
2.	CATHODE ANODE GATE
2.	RETURN INPUT OUTPUT

STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE STYLE 9: PIN 1. BASE 1 2. EMITTER 3. BASE 2 STYLE 14: PIN 1. EMITTER 2. COLLECTOR 3. BASE STYLE 19: PIN 1. GATE 2. ANODE 3. CATHODE STYLE 24: PIN 1. EMITTER 2. COLLECTOR/ANODE 3. CATHODE STYLE 29: PIN 1. NOT CONNECTED 2. ANODE 3. CATHODE STYLE 34: PIN 1. INPUT

2. GROUND 3. LOGIC

2. SOURCE 3. GATE STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2 STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. GATE 2. COLLECTOR 3. EMITTER

## GENERIC MARKING DIAGRAM\*

XXXXX XXXXX ALYW

XXXX = Specific Device Code

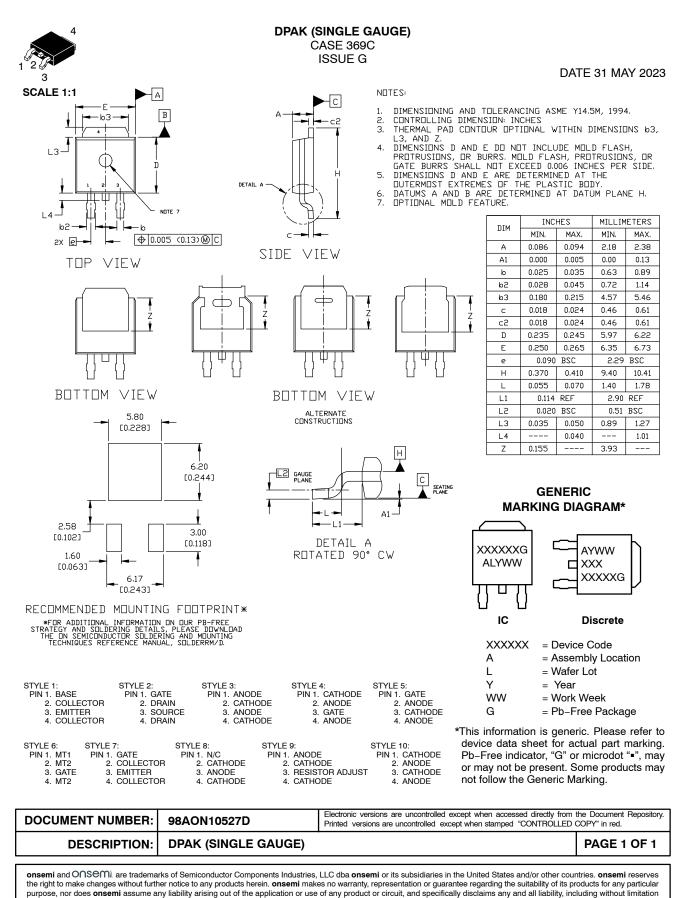
- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
  - = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

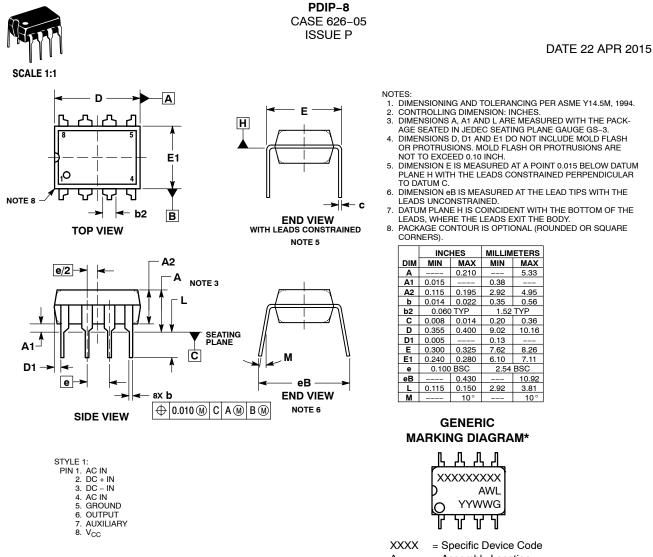
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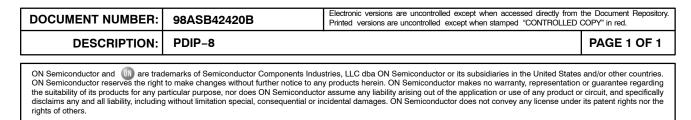




A = Assembly Location

- WL = Wafer Lot
- YY = Year
- WW = Work Week
- G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.



-Z-

# DURSEM



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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#### SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER EMITTER 5. BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: CATHODE 1 PIN 1. 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC COMMON CATHODE/VCC 3 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 COMMON ANODE/GND 8. STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5.

6.

7.

8 GATE 1

SOURCE 1/DRAIN 2

STYLE 3: DRAIN, DIE #1 PIN 1. DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 MIRROR 1 8. STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

#### DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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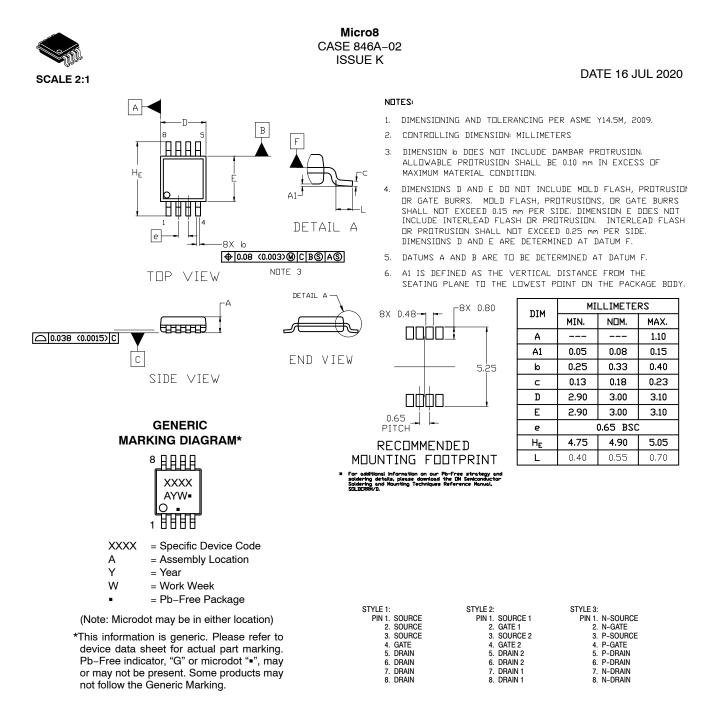
7.

8

COLLECTOR, #1

COLLECTOR, #1





 
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